FORM PTO 1449 (/		act 2	ATTY DOCKET NO. 03500.017983.	APPLICATION NO. 10/538,036		
U.S. DEPARTMENT OF COMMERCE PETERS OF REFERENCES CITED BY APPLICANT(S) (Use several sheets if necessary) MAY 0 4 2006 *EXAMINER DOCUMENT NUMBER DATE						
			FILING DATE June 8, 2005			-9
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/A.C./	2002/0195968	12/26/2002	Sanford, et al.	315	169.3	
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/A.C./	J. H. Wei, et al., "Improved stability of deuterated amorphous silicon thin film transistors", Journal Of Applied Physics, vol. 85, No. 1, pp, 543-550, (January 1, 1999).					
	H. Hamada, "Sharp Technical Report", No. 69 (1997), p. 75.					
EXAMINER /Afroza Chowdhury/			DATE CONSIDERED 09/18/2007			

Sheet 1 of 1

^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.